

IN74HC4052A

Analog Multiplexer/Demultiplexer

High-Performance Silicon-Gate CMOS

The IN74HC4052A utilises silicon-gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF leakage currents. These analog multiplexers/demultiplexers control analog voltages that may vary across the complete power supply range (from V_{CC} to V_{EE}).

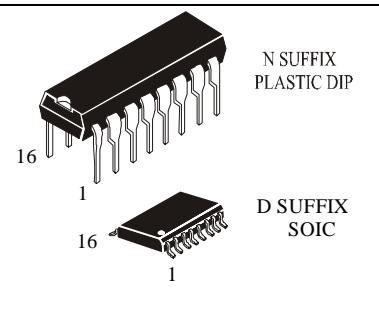
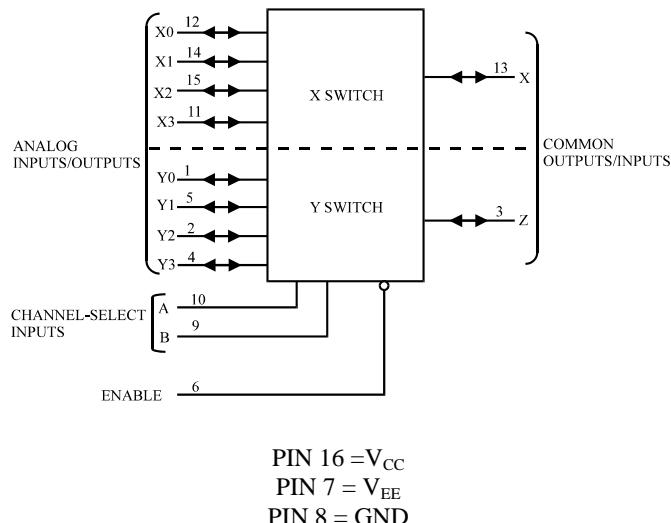
The Channel-Select inputs determine which one of the Analog Inputs/Outputs is to be connected, by means of an analog switch, to the Common Output/Input. When the Enable pin is high, all analog switches are turned off.

The Channel-Select and Enable inputs are compatible with standard CMOS outputs; with pull-up resistors, they are compatible with LS/ALS TTL outputs.

- Fast Switching and Propagation Speeds
- Low Crosstalk Between Switches
- Diode Protection on All Inputs/Outputs
- Analog Power Supply Range (V_{CC} - V_{EE}) = 2.0 to 12.0 V
- Digital (Control) Power Supply Range (V_{CC} -GND) = 2.0 to 6.0 V
- Low Noise

LOGIC DIAGRAM

Double-Pole, 4-Position
Plus Common Off



ORDERING INFORMATION

IN74HC4052AN Plastic DIP

IN74HC4052AD SOIC

$T_A = -55^\circ$ to 125° C for all packages

PIN ASSIGNMENT

Y0	1	●	16	V_{CC}
Y2	2		15	X2
Y	3		14	X1
Y3	4		13	X
Y1	5		12	X0
ENABLE	6		11	X3
V_{EE}	7		10	A
GND	8		9	B

FUNCTION TABLE

Enable	Control Inputs		ON Channels	
	Select			
	B	A		
L	L	L	Y0	X0
L	L	H	Y1	X1
L	H	L	Y2	X2
L	H	H	Y3	X3
H	X	X		None

H = high level

L = low level

X = don't care

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage (Referenced to GND) (Referenced to V_{EE})	-0.5 to +7.0 -0.5 to +14.0	V
V_{EE}	Negative DC Supply Voltage (Referenced to GND)	-7.0 to +0.5	V
V_{IS}	Analog Input Voltage	$V_{EE} - 0.5$ to $V_{CC} + 0.5$	V
V_{IN}	Digital Input Voltage (Referenced to GND)	-1.5 to $V_{CC} + 1.5$	V
I	DC Input Current Into or Out of Any Pin	± 25	mA
P_D	Power Dissipation in Still Air, Plastic DIP+ SO Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SO Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SO Package: - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V_{CC}	Positive Supply Voltage (Referenced to GND) (Referenced to V_{EE})	2.0 2.0	6.0 12.0	V	
V_{EE}	Negative DC Supply Voltage (Referenced to GND)	- 6.0	GND	V	
V_{IS}	Analog Input Voltage	V_{EE}	V_{CC}	V	
V_{IN}	Digital Input Voltage (Referenced to GND)	GND	V_{CC}	V	
V_{IO}^*	Static or Dynamic Voltage Across Switch	-	1.2	V	
T_A	Operating Temperature, All Package Types	-55	+125	°C	
t_r, t_f	Input Rise and Fall Time (Channel Select or Enable Inputs) (Figure 5)	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0	1000 500 400	ns

* For voltage drops across the switch greater than 1.2 V (switch on), excessive V_{CC} current may be drawn; i. e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range indicated in the Recommended Operating Conditions..

Unused digital input pins must be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused Analog I/O pins may be left open or terminated.

DC ELECTRICAL CHARACTERISTICS Digital Section (Voltages Referenced to GND) $V_{EE} = \text{GND}$,
Except Where Noted

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				-55°C to 25°C	$\leq 85^{\circ}\text{C}$	$\leq 125^{\circ}\text{C}$	
V_{IH}	Minimum High-Level Input Voltage, Channel-Select or Enable Inputs	$R_{ON} = \text{Per Spec}$	2.0 4.5 6.0	1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V
V_{IL}	Maximum Low -Level Input Voltage, Channel-Select or Enable Inputs	$R_{ON} = \text{Per Spec}$	2.0 4.5 6.0	0.3 0.9 1.2	0.3 0.9 1.2	0.3 0.9 1.2	V
I_{IN}	Maximum Input Leakage Current, Channel-Select or Enable Inputs	$V_{IN} = V_{CC}$ or GND, $V_{EE} = -6.0\text{ V}$	6.0	± 0.1	± 1.0	± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	Channel Select = V_{CC} or GND Enable = V_{CC} or GND $V_{IS} = V_{CC}$ or GND $V_{IO} = 0\text{ V}$ $V_{EE} = \text{GND}$ $V_{EE} = -6.0\text{ V}$	6.0 6.0	2 8	20 80	40 160	μA

DC ELECTRICAL CHARACTERISTICS Analog Section

Symbol	Parameter	Test Conditions	V_{CC} V	V_{EE} V	Guaranteed Limit			Unit
					25°C to -55°C	$\leq 85^{\circ}\text{C}$	$\leq 125^{\circ}\text{C}$	
R_{ON}	Maximum “ON” Resistance	$V_{IN} = V_{IL}$ or V_{IH} $V_{IS} = V_{CC}$ to V_{EE} $I_S \leq 2.0\text{ mA}$	4.5 4.5 6.0	0.0 -4.5 -6.0	190 120 100	240 150 125	280 170 140	Ω
		$V_{IN} = V_{IL}$ or V_{IH} $V_{IS} = V_{CC}$ or V_{EE} (Endpoints) $I_S \leq 2.0\text{ mA}$	4.5 4.5 6.0	0.0 -4.5 -6.0	150 100 80	190 125 100	230 140 115	
ΔR_{ON}	Maximum Difference in “ON” Resistance Between Any Two Channels in the Same Package	$V_{IN} = V_{IL}$ or V_{IH} $V_{IS} = 1/2(V_{CC} - V_{EE})$ $I_S \leq 2.0\text{ mA}$	4.5 4.5 6.0	0.0 -4.5 -6.0	30 12 10	35 15 12	40 18 14	Ω
I_{OFF}	Maximum Off- Channel Leakage Current, Any One Channel	$V_{IN} = V_{IL}$ or V_{IH} $V_{IO} = V_{CC} - V_{EE}$ Switch Off	6.0	-6.0	0.1	0.5	1.0	μA
	Maximum Off- Channel Leakage Current, Common Channel	$V_{IN} = V_{IL}$ or V_{IH} $V_{IO} = V_{CC} - V_{EE}$ Switch Off	6.0	-6.0	0.1	1.0	2.0	
I_{ON}	Maximum On- Channel Leakage Current, Channel to Channel	$V_{IN} = V_{IL}$ or V_{IH} Switch to Switch = $V_{CC} - V_{EE}$	6.0	-6.0	0.1	1.0	2.0	μA

AC ELECTRICAL CHARACTERISTICS($C_L=50\text{pF}$, Input $t_r=t_f=6.0\text{ ns}$)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			25°C to -55°C	$\leq 85^\circ\text{C}$	$\leq 125^\circ\text{C}$	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Channel-Select to Analog Output (Figures 1 and 2)	2.0 4.5 6.0	370 74 63	465 93 79	550 110 94	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay , Analog Input to Analog Output (Figures 3 and 4)	2.0 4.5 6.0	60 12 10	75 15 13	90 18 15	ns
t_{PLZ}, t_{PHZ}	Maximum Propagation Delay , Enable to Analog Output (Figures 5 and 6)	2.0 4.5 6.0	290 58 49	364 73 62	430 86 73	ns
t_{PZL}, t_{PZH}	Maximum Propagation Delay , Enable to Analog Output (Figures 5 and 6)	2.0 4.5 6.0	345 69 59	435 87 74	515 103 87	ns
$t_{PLZ}, t_{PHZ}, t_{PZL}, t_{PZH}$	Maximum Propagation Delay, Channel-Select to Analog Input (Figures 5 and 6)	2.0 4.5 6.0	370 74 63	465 93 79	550 110 94	ns
C_{IN}	Maximum Input Capacitance, Channel-Select or Enable Inputs	-	10	10	10	pF
$C_{I/O}$	Maximum Capacitance Analog I/O Common O/I Feedthrough	All Switches Off	-	35	35	pF
			-	80	80	
			-	1.0	1.0	

C_{PD}	Power Dissipation Capacitance (Per Package) Used to determine the no-load dynamic power consumption: $P_D=C_{PD}V_{CC}^2f+I_{CC}V_{CC}$	Typical @ 25°C , $V_{CC}=5.0\text{ V}$, $V_{EE}=0\text{ V}$			pF
		80			

ADDITIONAL APPLICATION CHARACTERISTICS (GND = 0.0 V)

Symbol	Parameter	Test Conditions	V _{CC}	V _{EE}	Limit	Unit
			V	V	25 °C	
B _W	Maximum On-Channel Bandwidth or Minimum Frequency Response	f _{in} =1 MHz Sine Wave Adjust f _{in} Voltage to Obtain 0 dBm at V _{OS} Increase f _{in} Frequency Until dB Meter Reads -3 dB R _L =50 Ω, C _L =10 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	95 95 95	MHz
K _{Doff}	Off-Channel Feedthrough Isolation	f _{in} = Sine Wave Adjust f _{in} Voltage to Obtain 0 dBm at V _{IS} f _{in} = 10 kHz, R _L =600 Ω, C _L =50 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	-50 -50 -50	dB
		f _{in} = 1.0 MHz, R _L =50 Ω, C _L =10 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	-40 -40 -40	
		f _{in} ≤ 1 MHz Square Wave (t _r = t _f = 6 ns) Adjust R _L at Setup so that I _S = 0 A Enable = GND R _L =600 Ω, C _L =50 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	25 105 135	mVpp
		R _L =10 Ω, C _L =10 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	35 145 190	
K _{Don}	Crosstalk Between Any Two Switches	f _{in} = Sine Wave Adjust f _{in} Voltage to Obtain 0 dBm at V _{IS} f _{in} = 10 kHz, R _L =600 Ω, C _L =50 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	-50 -50 -50	dB
		f _{in} = 1 MHz, R _L =50 Ω, C _L =10 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	-60 -60 -60	
		f _{in} = 1 kHz, R _L =10 kΩ, C _L =50 pF THD = THD _{Measured} - THD _{Source} V _{IS} =4.0 V _{PP} sine wave V _{IS} =8.0 V _{PP} sine wave V _{IS} =11.0 V _{PP} sine wave	2.25 4.50 6.00	-2.25 -4.50 -6.00	0.10 0.08 0.05	%

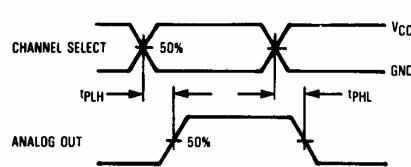
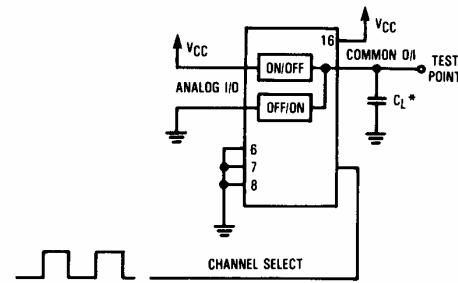


Figure 1. Switching Waveforms



* Includes all probe and jig capacitance.

Figure 2. Test Set-U_P, Channel Select to Analog Out

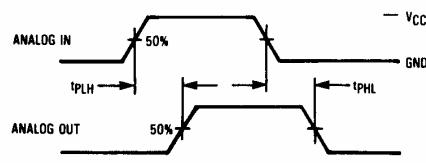
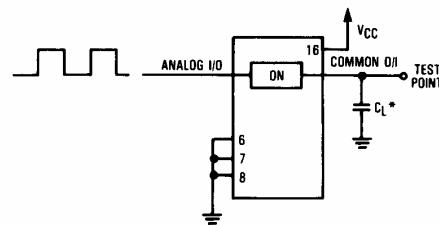


Figure 3. Switching Waveforms



* Includes all probe and jig capacitance.

Figure 4. Test Set-U_P, Analog In to Analog Out

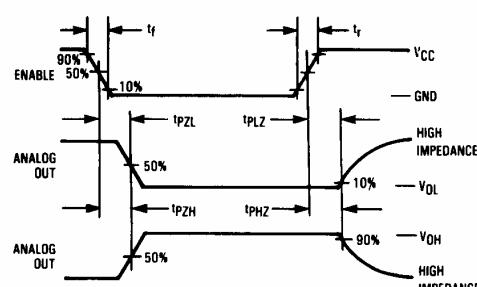


Figure 5. Switching Waveforms

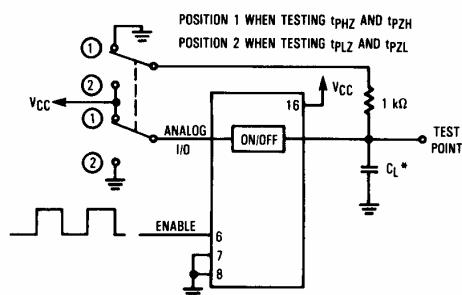
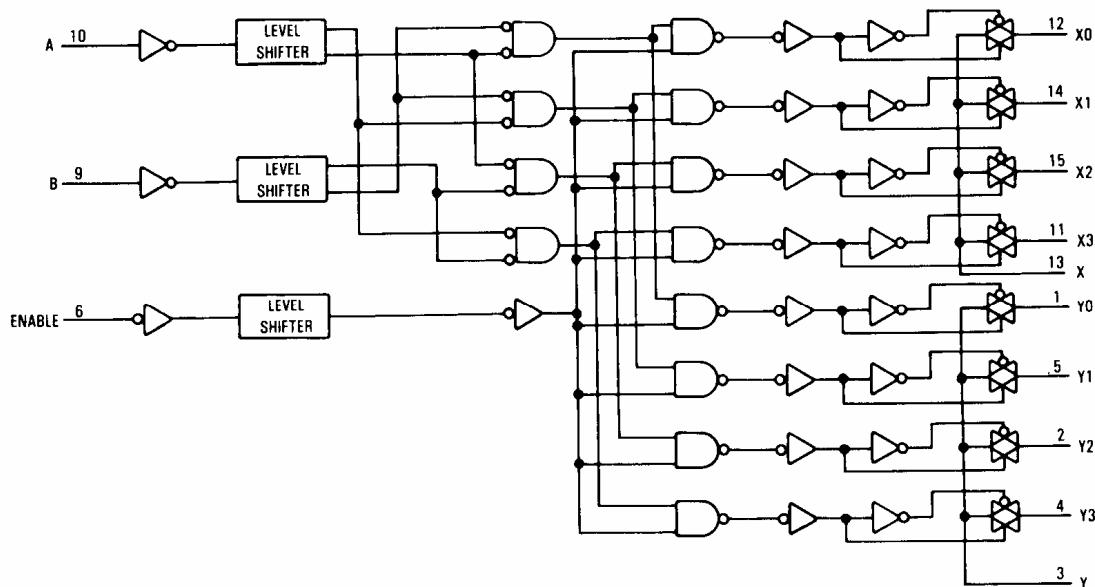
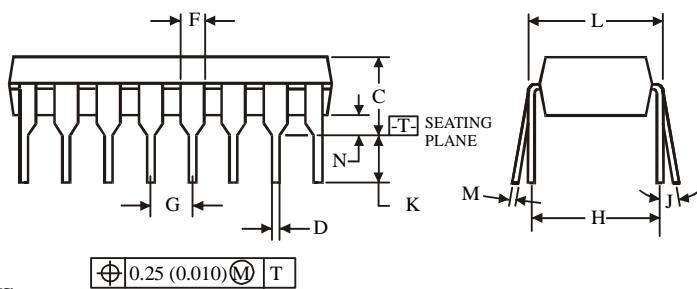
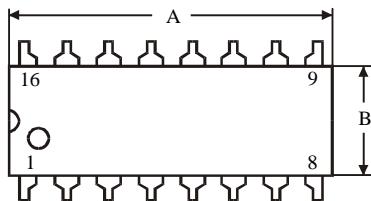


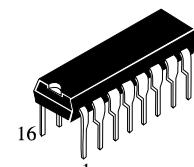
Figure 6. Test Set-U_P, Enable to Analog Out

EXPANDED LOGIC DIAGRAM

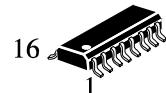
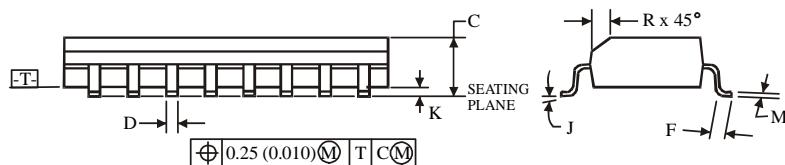
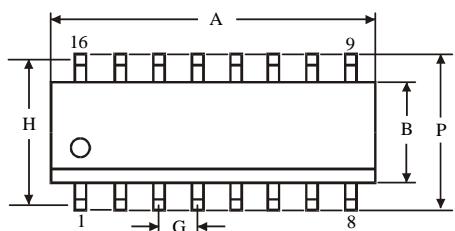
**N SUFFIX PLASTIC DIP
(MS - 001BB)**
**NOTES:**

- Dimensions "A", "B" do not include mold flash or protrusions.

Maximum mold flash or protrusions 0.25 mm (0.010) per side.



Dimension, mm		
Symbol	MIN	MAX
A	18.67	19.69
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

**D SUFFIX SOIC
(MS - 012AC)**


Dimension, mm		
Symbol	MIN	MAX
A	9.8	10
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

NOTES:

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.